NSN 5961-00-188-3974

Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-188-3974 **Inclosure Material:** Metal and glass **Overall Length:** Between 0.180 inches and 0.210 inches **Terminal Length:** 1.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Function For Which Designed:** Detector **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to emitter voltage/static/base open and 7.0 emitter to collector voltage, dc and 80.0 collector to base voltage/static/emitter open **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

Yes - demil/mli

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